

Cascadable Silicon Bipolar MMIC Amplifier

Technical Data

MSA-0770

Features

- **Cascadable 50 Ω Gain Block**
- **Low Operating Voltage:**
4.0 V Typical V_d
- **3 dB Bandwidth:**
DC to 2.5 GHz
- **13.0 dB Typical Gain at 1.0 GHz**
- **Unconditionally Stable ($k > 1$)**
- **Hermetic, Gold-ceramic Microstrip Package**

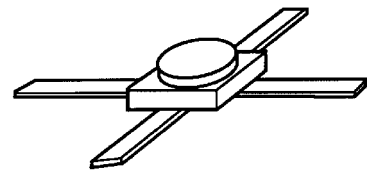
Description

The MSA-0770 is a high performance silicon bipolar Monolithic Microwave Integrated Circuit (MMIC) housed in a hermetic,

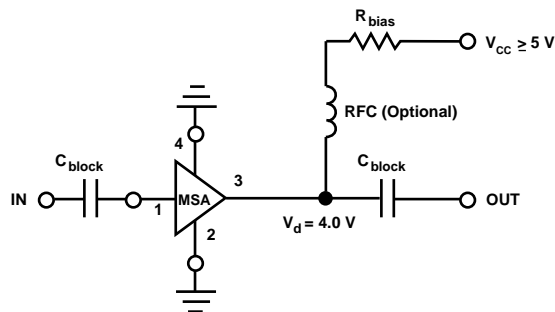
high reliability package. This MMIC is designed for use as a general purpose 50 Ω gain block. Typical applications include narrow and broad band IF and RF amplifiers in industrial and military applications.

The MSA-series is fabricated using HP's 10 GHz f_T , 25 GHz f_{MAX} silicon bipolar MMIC process which uses nitride self-alignment, ion implantation, and gold metallization to achieve excellent performance, uniformity and reliability. The use of an external bias resistor for temperature and current stability also allows bias flexibility.

70 mil Package



Typical Biasing Configuration



MSA-0770 Absolute Maximum Ratings

Parameter	Absolute Maximum ^[1]
Device Current	60 mA
Power Dissipation ^[2,3]	275 mW
RF Input Power	+13 dBm
Junction Temperature	200°C
Storage Temperature	-65 to 200°C

Thermal Resistance^[2,4]:

$$\theta_{jc} = 130^{\circ}\text{C}/\text{W}$$

Notes:

1. Permanent damage may occur if any of these limits are exceeded.
2. $T_{\text{CASE}} = 25^{\circ}\text{C}$.
3. Derate at $7.7 \text{ mW}/^{\circ}\text{C}$ for $T_{\text{C}} > 164^{\circ}\text{C}$.
4. This small spot size of this technique results in a higher, though more accurate determination of θ_{jc} than do alternate methods. See MEASUREMENTS section "Thermal Resistance" for more information.

Electrical Specifications^[1], $T_{\text{A}} = 25^{\circ}\text{C}$

Symbol	Parameters and Test Conditions: $I_{\text{d}} = 22 \text{ mA}$, $Z_0 = 50 \Omega$	Units	Min.	Typ.	Max.
G_{P}	Power Gain ($ S_{21} ^2$)	dB	12.5	13.5	14.5
ΔG_{P}	Gain Flatness	dB		± 0.6	± 1.0
$f_{3 \text{ dB}}$	3 dB Bandwidth	GHz		2.5	
VSWR	Input VSWR			2.0:1	
	Output VSWR			1.6:1	
NF	50 Ω Noise Figure	dB		4.5	
$P_{1 \text{ dB}}$	Output Power at 1 dB Gain Compression	dBm		5.5	
IP_3	Third Order Intercept Point	dBm		19.0	
t_{D}	Group Delay	psec		130	
V_{d}	Device Voltage	V	3.6	4.0	4.4
dV/dT	Device Voltage Temperature Coefficient	mV/ $^{\circ}\text{C}$		-7.0	

Note:

1. The recommended operating current range for this device is 15 to 40 mA. Typical performance as a function of current is on the following page.

MSA-0770 Typical Scattering Parameters ($Z_0 = 50 \Omega$, $T_A = 25^\circ\text{C}$, $I_d = 22 \text{ mA}$)

Freq. GHz	S_{11}		S_{21}			S_{12}			S_{22}	
	Mag	Ang	dB	Mag	Ang	dB	Mag	Ang	Mag	Ang
0.1	.04	-7	13.5	4.74	175	-18.6	.118	2	.20	-10
0.2	.05	-11	13.5	4.72	170	-18.4	.120	2	.19	-18
0.4	.06	-24	13.4	4.70	160	-18.4	.121	6	.20	-34
0.6	.08	-38	13.4	4.65	151	-18.1	.124	7	.21	-50
0.8	.10	-48	13.2	4.58	141	-17.8	.133	9	.23	-76
1.0	.12	-58	13.0	4.47	131	-17.5	.133	9	.23	-76
1.5	.20	-82	12.3	4.12	107	-16.6	.148	10	.23	-101
2.0	.30	-107	11.6	3.82	85	-15.7	.163	8	.22	-116
2.5	.37	-123	10.4	3.33	70	-15.3	.171	7	.19	-116
3.0	.42	-140	9.0	2.83	52	-15.4	.170	3	.20	-111
3.5	.46	-154	7.7	2.42	37	-15.4	.170	1	.23	-107
4.0	.47	-167	6.4	2.08	23	-15.5	.169	-4	.29	-107
5.0	.47	163	4.2	1.63	-1	-15.5	.167	-9	.35	-116
6.0	.51	131	2.3	1.30	-23	-15.9	.160	-11	.38	-133

A model for this device is available in the DEVICE MODELS section.

Typical Performance, $T_A = 25^\circ\text{C}$

(unless otherwise noted)

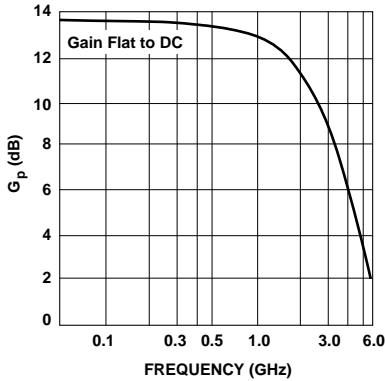


Figure 1. Typical Power Gain vs. Frequency, $I_d = 22 \text{ mA}$.

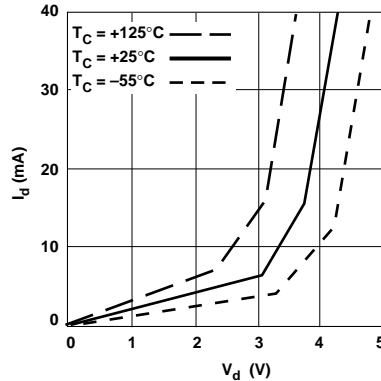


Figure 2. Device Current vs. Voltage.

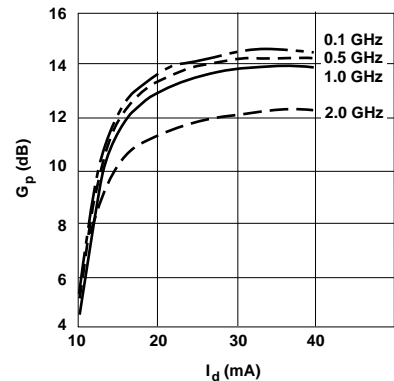


Figure 3. Power Gain vs. Current.

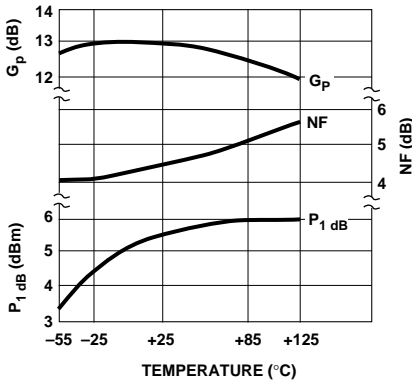


Figure 4. Output Power at 1 dB Gain Compression, NF and Power Gain vs. Case Temperature, $f = 1.0 \text{ GHz}$, $I_d = 22 \text{ mA}$.

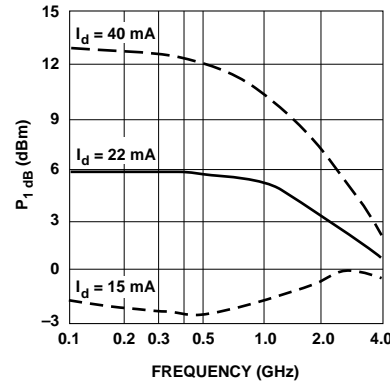


Figure 5. Output Power at 1 dB Gain Compression vs. Frequency.

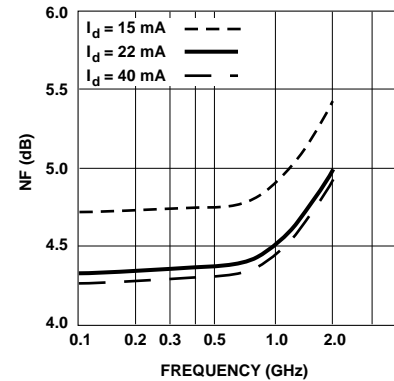
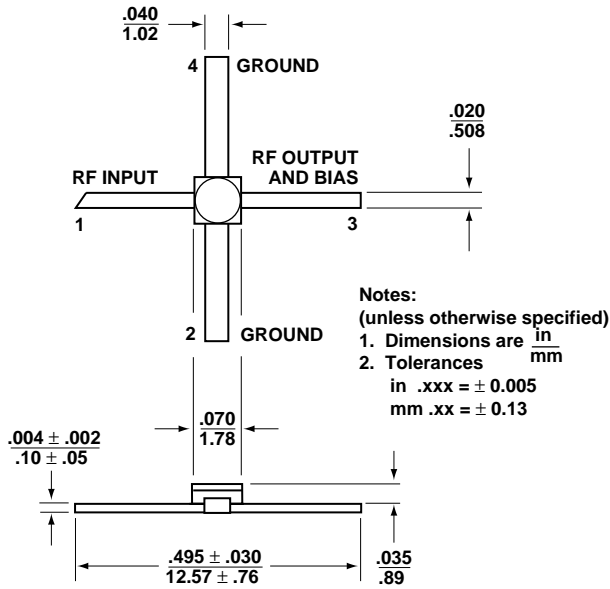


Figure 6. Noise Figure vs. Frequency.

70 mil Package Dimensions



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